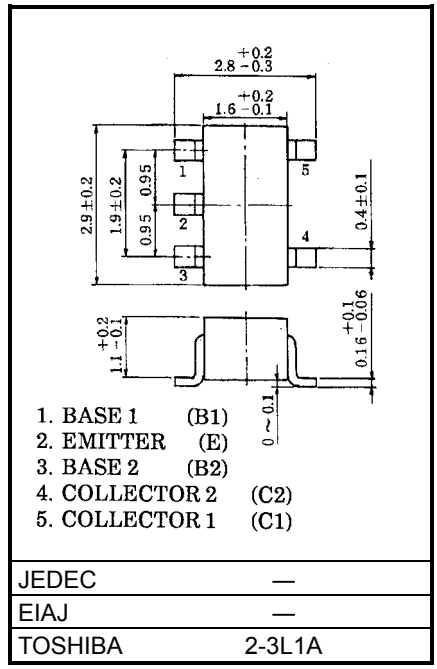
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1507,RN1508,RN1509

Unit: mm

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

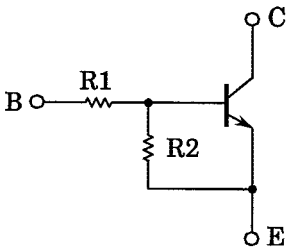
- Including two devices in SMV
  (super mini type with 5 leads)With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2507~RN2509



JEDEC	—
EIAJ	—
TOSHIBA	2-3L1A

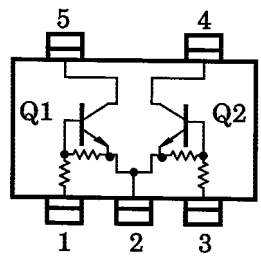
Weight: 0.014g

Equivalent Circuit and Bias Resister Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1907	10	47
RN1908	22	47
RN1909	47	22

Equivalent Circuit (Top View)



Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

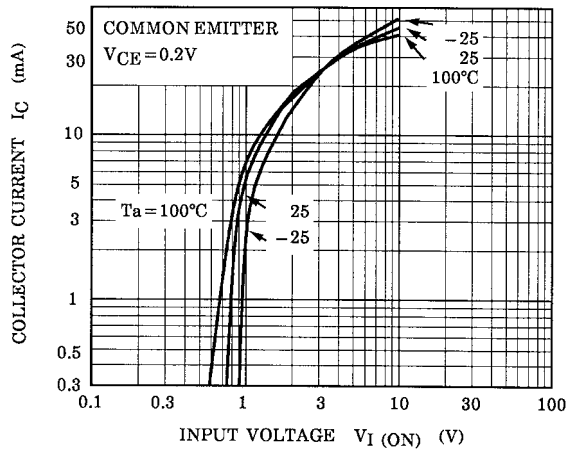
Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN1507~1509	V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage	RN1507	V_{EBO}	6	V
	RN1508		7	
	RN1509		15	
Collector current	RN1507~1509	I_C	100	mA
Collector power dissipation		P_C *	300	mW
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55~150	°C

* : Total rating

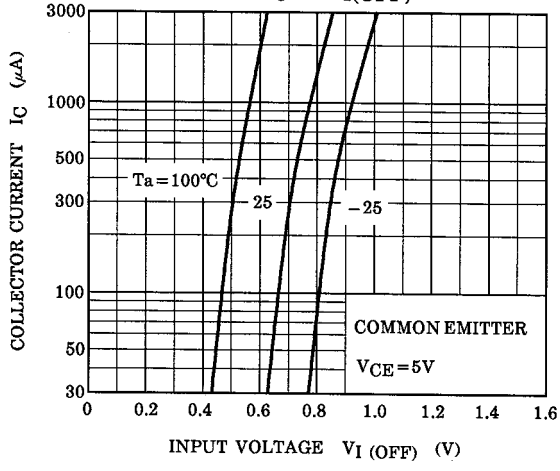
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1507~1509	I_{CBO}	—	V_{CB} = 50V, I_E = 0	—	—	100	nA
		I_{CEO}		V_{CE} = 50V, I_B = 0	—	—	500	nA
Emitter cut-off current	RN1507	I_{EBO}	—	V_{EB} = 6V, I_C = 0	0.081	—	0.15	mA
	RN1508			V_{EB} = 7V, I_C = 0	0.078	—	0.145	
	RN1509			V_{EB} = 15V, I_C = 0	0.167	—	0.311	
DC current gain	RN1507	h_{FE}	—	V_{CE} = 5V, I_C = 10mA	80	—	—	
	RN1508				80	—	—	
	RN1509				70	—	—	
Collector-emitter saturation voltage	RN1507~1509	$V_{CE\ (sat)}$	—	I_C = 5mA, I_B = 0.25mA	—	0.1	0.3	V
Input voltage (ON)	RN1507	$V_{I\ (ON)}$	—	V_{CE} = 0.2V, I_C = 5mA	0.7	—	1.8	V
	RN1508				1.0	—	2.6	
	RN1509				2.2	—	5.8	
Input voltage (OFF)	RN1507	$V_{I\ (OFF)}$	—	V_{CE} = 5V, I_C = 0.1mA	0.5	—	1.0	V
	RN1508				0.6	—	1.16	
	RN1509				1.5	—	2.6	
Transition frequency	RN1507~1509	f_T	—	V_{CE} = 10V, I_C = 5mA	—	250	—	MHz
Collector Output capacitance	RN1507~1509	C_{ob}	—	V_{CB} = 10V, I_E = 0, f = 1MHz	—	3	6	pF
Input resistor	RN1507	R1	—		7	10	13	kΩ
	RN1508				15.4	22	28.6	
	RN1509				32.9	47	61.1	
Resistor ratio	RN1507	R1/R2	—		0.191	0.213	0.232	
	RN1508				0.421	0.468	0.515	
	RN1509				1.92	2.14	2.35	

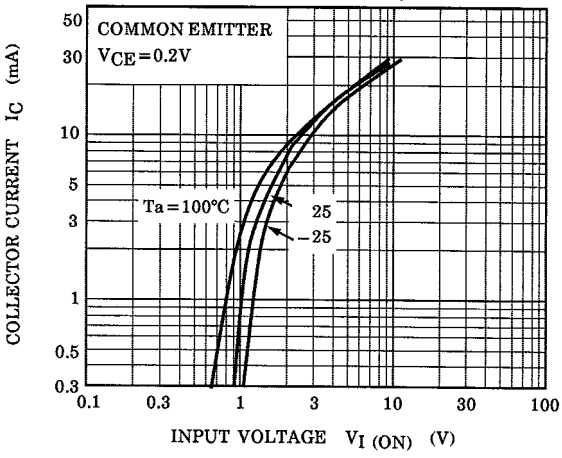
RN1507 I_C – $V_{I\,(ON)}$



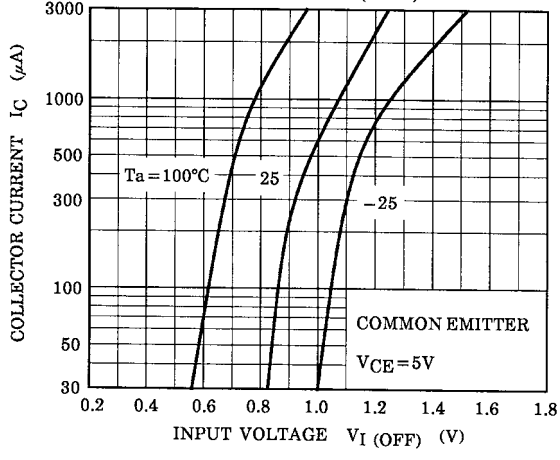
RN1507 I_C – $V_{I(OFF)}$



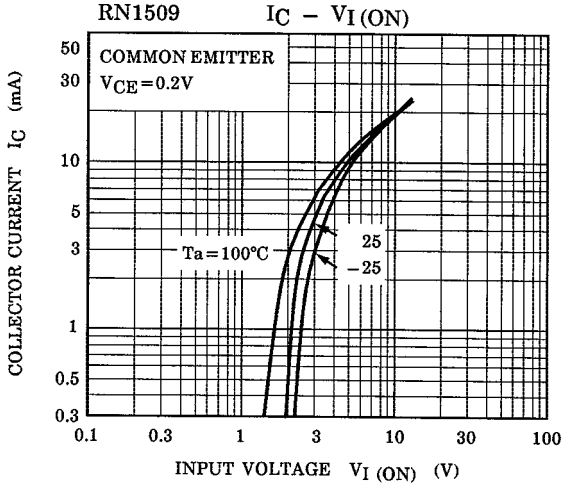
RN1508 I_C – $V_{I\,(ON)}$



RN1508 I_C – $V_{I\,(OFF)}$



RN1509 I_C – $V_{I\,(ON)}$



RN1509 I_C – $V_{I\,(OFF)}$